NSN 5962-01-216-0733

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-216-0733 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.245 inches and 0.280 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 400.0 milliwatts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Programmable and schottky and monolithic and bipolar **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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